

2-pack-integrated intelligent Power System

SKiiP 1814 GB12E4-3DUL V2

Features

- Intelligent Power Module
- Integrated current and temperature measurement
- Integrated DC-link measurement
- · Solder free power section
- IGBT4 and CAL4F technology
- $T_{jmax} = 175$ °C
- Safety isolated switching and sensor signals
- Digital signal transmission
- CAN Interface
- 100% tested IPM
- RoHS compliant
- UL file no. E242581

Typical Applications*

- Renewable energies
- Traction
- Elevators
- Industrial drives

Remarks

For further information please refer to SKiiP®4 Technical Explanation

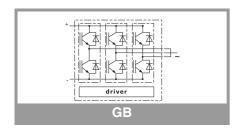
Footnotes

1) With assembly of suitable MKP capacitor per terminal

 $^{2)}$ The specified maximum operation junction temperature T_{vjop} is 150°C

Absolute Maximum Ratings							
Symbol	Conditions		Values	Unit			
System	•						
V _{CC} 1)	Operating DC link	voltage	900	V			
V _{isol}	DC, t = 1 s, each p	olarity	4300	V			
I _{t(RMS)}	per AC terminal, rm	ns, sinusoidal current	500	Α			
I _{max (peak)}	max. peak current	of power section	2700	А			
I _{FSM}	$T_j = 175 {}^{\circ}\text{C}, t_p = 10$	ms, sin 180°	11907	А			
l ² t	$T_j = 175 {}^{\circ}\text{C}, t_p = 10$	ms, diode	709	kA ² s			
f _{out}	fundamental outpu (sinusoidal)	t frequency	1	kHz			
T _{stg}	storage temperatu	re	-40 85	°C			
IGBT		<u>.</u>					
V _{CES}	T _j = 25 °C		1200	V			
Ic	T _i = 175 °C	T _s = 25 °C	2345	Α			
	1 _j = 1/5 C	T _s = 70 °C	1906	Α			
I _{Cnom}			1800	А			
T _j ²⁾	junction temperature		-40 175	°C			
Diode							
V_{RRM}	T _j = 25 °C		1200	V			
I _F	T _i = 175 °C	T _s = 25 °C	1776	Α			
	1 j = 175 C	T _s = 70 °C	1408	А			
I _{Fnom}			1800	Α			
T _j ²⁾	junction temperature		-40 175 °C				
Driver							
Vs	power supply		19.2 28.8	V			
V_{iH}	input signal voltage (high)		V _s + 0.3	V			
dv/dt	secondary to prima	ary side	75	kV/μs			
f _{sw}	switching frequenc	у	15	kHz			

Characteristics								
Symbol	Conditions		min.	typ.	max.	Unit		
IGBT								
V _{CE(sat)}	I _C = 1800 A	T _j = 25 °C		2.01	2.26	V		
	at terminal	T _j = 150 °C		2.49	2.69	V		
V_{CE0}		T _j = 25 °C		0.80	0.90	V		
		T _j = 150 °C		0.70	0.80	V		
r _{CE}	at terminal	T _j = 25 °C		0.67	0.76	mΩ		
		T _j = 150 °C		1.00	1.05	mΩ		
E _{on} + E _{off}	I _C = 1800 A	V _{CC} = 600 V		703		mJ		
	T _j = 150 °C	V _{CC} = 900 V		1260		mJ		
R _{th(j-s)}	per IGBT switch				0.021	K/W		
R _{th(j-r)}	per IGBT switch				0.0127	K/W		





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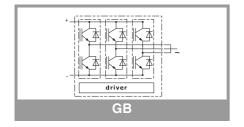
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Character	ristics					
Symbol	Conditions		min.	typ.	max.	Unit
Diode			•			
$V_F = V_{EC}$	I _F = 1800 A	T _i = 25 °C		2.33	2.65	V
	at terminal	T _j = 150 °C		2.35	2.66	V
V _{F0}		T _j = 25 °C		1.30	1.50	٧
		T _j = 150 °C		0.90	1.10	V
r _F	at tarresia al	T _j = 25 °C		0.57	0.64	mΩ
	at terminal	T _j = 150 °C		0.81	0.87	mΩ
E _{rr}	I _F = 1800 A	V _R = 600 V		119		mJ
	T _j = 150 °C	V _R = 900 V		150		mJ
R _{th(j-s)}	per diode switch				0.0375	K/W
R _{th(j-r)}	per diode switch				0.024	K/W
Driver	1					
Vs	supply voltage non	stabilized	19.2	24	28.8	٧
I _{S0}	bias current @V _s =	24V, $f_{sw} = 0$, $I_{AC} = 0$		230		mA
Is	$k_1 = 24 \text{ mA/kHz}, k_2$ $f_{\text{out}} = 50 \text{Hz}, \text{ sinusoid}$		= 230	+ k ₁ * f _{sw}	+ k ₂ * l _{AC} ²	mA
V_{IT+}	input threshold vol	tage (HIGH)	0,7*V _s			٧
V _{IT-}	input threshold vol	tage (LOW)	0,3*V _s		V	
R _{IN}	input resistance			13		kΩ
C _{IN}	input capacitance 1		nF			
t _{pRESET}	error memory reset time			500		ms
t _{pReset(OCP)}	Over current reset	time				μs
t _{TD}	top / bottom switch	interlock time		3		μs
t _{jitter}	jitter clock time			50	58	ns
t _{SIS}	short pulse suppre	ssion time		0.6		μs
t _{POR}	Power-On-Reset c	ompleted			1	S
I _{digiout}	digital output sink ((HALT-signal)	current			16	mA
V _{it+ HALT}	input threshold volt (Low>High)	tage HIGH HALT	0,6*V _s			V
V _{it-HALT}	input threshold vol (High> Low)	tage LOW HALT			0.4*V _s	٧
t _{d(err)}	Error delay time (fr HALT), (depends o		3		370	μs
I _{TRIPSC}	over current trip lev	/el	2700			A _{PEAK}
I _{LL}				n.a.		A _{PEAK}
T_{trip}	over temperature t	rip level	128	135	142	°C
T _{DriverTrip}	over temperature F	PCB trip level	113	120	124	°C
V _{DCtrip}	over voltage trip le	vel,	950	980	1010	V
V _{DCtripLL}				n.a.		V





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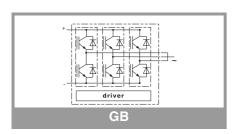
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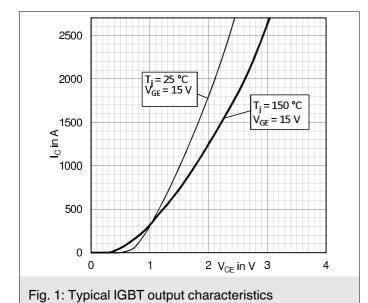
Characteristics								
Symbol	Conditions	min.	typ.	max.	Unit			
System								
t _{d(on)IO}	V _{CC} = 600 V I _C = 1800 A	turn on propagation delay time		2.8		μs		
t _{d(off)IO}	$T_j = 25 ^{\circ}\text{C}$	turn off propagation delay time	3.8			μs		
dV _{CE} /dt _{on}	T _i = 25 °C	$I_C = 0 A$		9		kV/μs		
	$V_{CC} = 600 \text{ V}$	$I_C = 1800 \text{ A}$		3		kV/μs		
dV_{CE}/dt_{off}		$I_C = 1800 A$		4		kV/μs		
R _{th(s-a)}	flow rate = 610 m ³ /h, T _a =25°C, 500m above sea level				0.024	K/W		
R _{CC'+EE'}	measured per switch, T _s = 25 °C			0.09		mΩ		
L _{CE}	commutation inductance			6		nΗ		
Сснс	coupling capacitance secondary to heat sink		4.8		nF			
C _{ps}	coupling capacitates	coupling capacitance primary to secondary		0.067		nF		
I _{CES} + I _{RD}	V _{GE} = 0 V, V _{CE} = 1200 V, T _j = 25 °C		0.157			mA		
M _{dc}	DC terminals		6		8	Nm		
M _{ac}	AC terminals		13		15	Nm		
w	SKiiP System w/o heat sink			2.48		kg		
Wh	heat sink			5.9		kg		

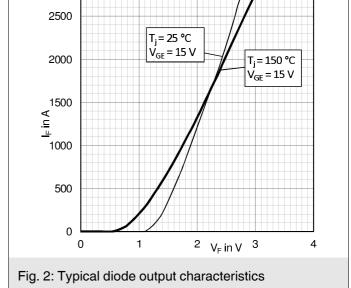
Isolation coordination acc. to EN 50178 and IEC 61800-5-1	
Maximum grid RMS voltage, line-to-line, grounded delta mains	480V+20%
Installation altitude for maximum grid RMS voltage, line-to-line, grounded delta mains	4000m
Maximum grid RMS voltage, line-to-line, star point grounded mains	480V+20%
Installation altitude for maximum grid RMS voltage, line-to-line, star point grounded mains	8000m
Maximum transient peak voltage between low voltage circuit and mains	1900V
Pollution degree acc. to IEC 60664-1 outside the moulded power section	2
Overvoltage cat. acc. to IEC 60664-1 for mains	III
Overvoltage cat. acc. to UL 840 within mains	I
Overvoltage cat. acc. to UL 840 between mains and ground	III
Overvoltage cat. acc. to UL 840 between mains and low voltage circuit	III
Basic isolation	between heat sink and mains
Reinforced isolation	between low voltage circuit and mains
Protection level acc. to IEC 60529	IP00

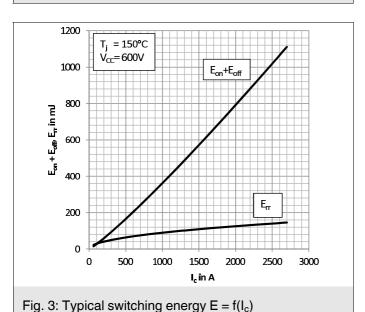
Environmental conditions acc. to IEC 60721

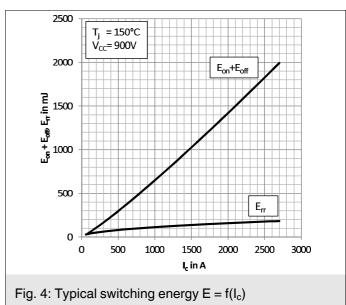
	Storage	Transportation	Operation stationary use at weather protected locations	Operating ground vehicle installations	Operating ship environment
Climatic conditions	1K2 ₍₁₎	2K2 ₍₁₎	3K3 ₍₁₎	5K1 ₍₁₎	6K1 ₍₁₎
Biological conditions	1B1	2B1	3B1	5B1	6B1
Chemically active substances (excluded: salt spray)	1C2	2C1	3C2	5C2	6C2
Mechanically active substances	181	281	381	581	6S1
Mechanical conditions	1M3	(4)	3M6 ₍₂₎	5M3 ₍₃₎	6M3
Contaminating fluids				5F1	

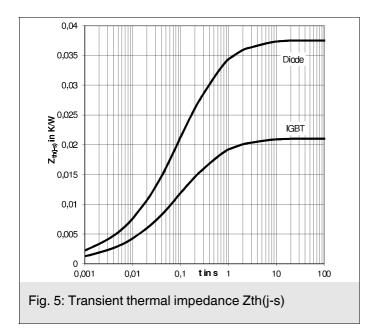
- (1) expanded temperature range: -40°C / +85°C. Please note: by operation near 85°C the life time of product is reduced.
- (2) 3M7 possible, but due to the mechanic load capacity of external components like DC-Link capacitors limited to 3M6
- (3) 5M3 without impact of foreign bodies, stones
- (4) no declaration due to customer-specific packing

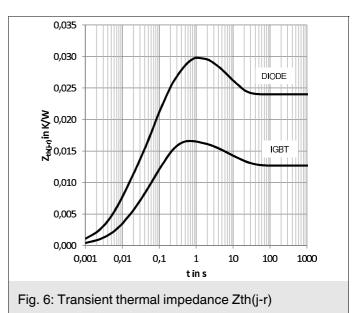












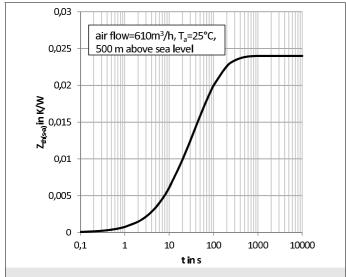


Fig. 7: Transient thermal impedance Zth(s-a)

	R _{th} [K/W]							
	1 2 3 4 5							
$Z_{th(j-s)}$ I	0,0015	0,0075	0,0083	0,0025	0,0012			
Z _{th(j-s)} D	0,0026	0,0134	0,0149	0,0045	0,0021			
Z _{th(j-r)} I	0,0035	0,0048	0,0087	-0,0018	-0,0025			
Z _{th(j-r)} D	0,0077	0,0135	0,0098	-0,0070	0,0000			
Z _{th(s-a)}	0,0064	0,0136	0,0040	0,0000	0,0000			
		tau [s]						
	1	2	3	4	5			
$Z_{th(j-s)}$ I	3,6500	0,4100	0,0650	0,0090	0,0008			
$Z_{th(j-s)}$ D	3,6500	0,4100	0,0650	0,0090	0,0008			
$Z_{th(j-r)}$ I	0,0120	0,0470	0,1400	4,9000	16,000			
$Z_{th(j-r)}$ D	0,0084	0,0600	0,3200	8,6000	1,0000			
$Z_{th(s-a)}$	13,200	51,000	157,00	1,0000	1,0000			

Fig. 8: Coefficients of thermal impedances

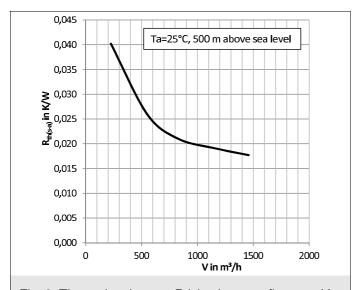


Fig. 9: Thermal resistance Rth(s-a) versus flow rate V

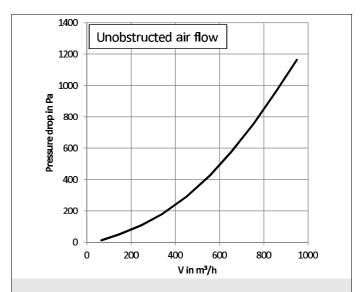
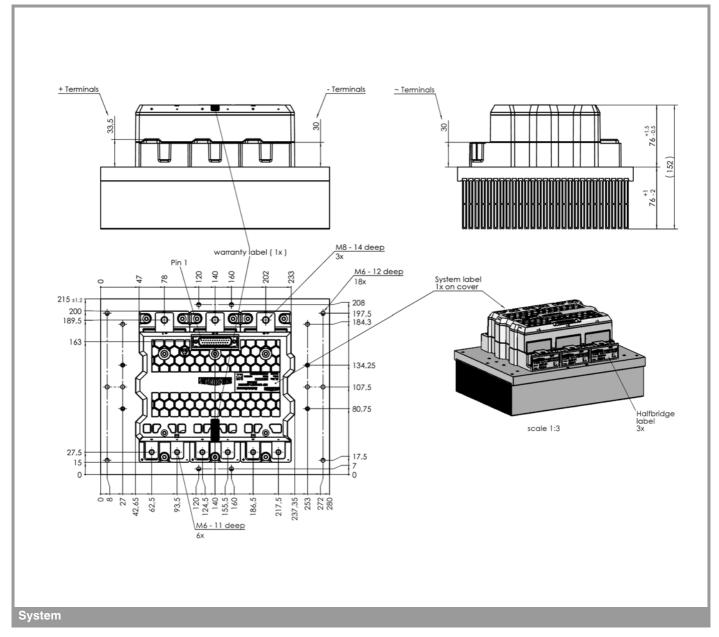


Fig. 10: Pressure drop Δp versus flow rate V



This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, chapter IX.

*IMPORTANT INFORMATION AND WARNINGS

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